



# PJA3431

## 20V P-Channel Enhancement Mode MOSFET – ESD Protected

Voltage      -20 V      Current      -1.5A

### Features

- R<sub>DS(ON)</sub> , V<sub>GS</sub>@-4.5V, I<sub>D</sub>@-1.5A<325mΩ
- R<sub>DS(ON)</sub> , V<sub>GS</sub>@-2.5V, I<sub>D</sub>@-1.2A<420mΩ
- R<sub>DS(ON)</sub> , V<sub>GS</sub>@-2.5V, I<sub>D</sub>@-0.5A<600mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in comply with EU RoHS 2011/65/EU directives.
- Green molding compound as per IEC61249 Std.  
(Halogen Free)

### Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams
- Marking : A31

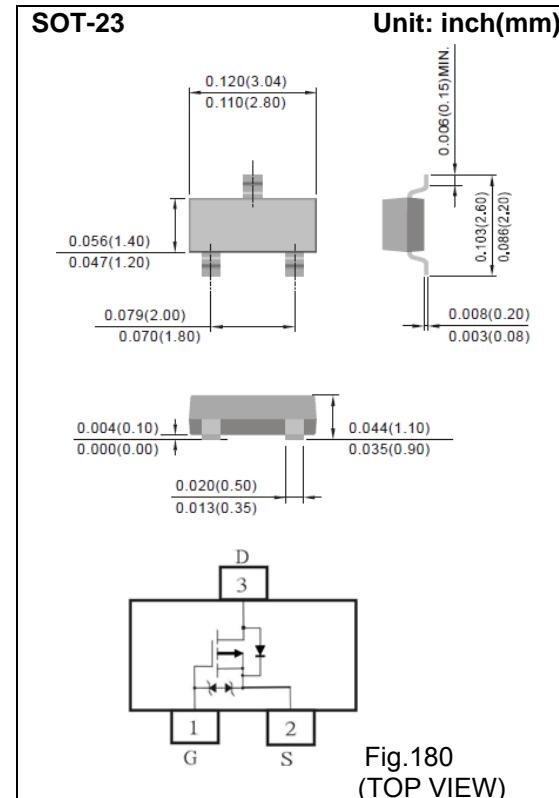


Fig.180  
(TOP VIEW)

### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL                            | LIMIT   | UNITS |
|---|-----------------------------------|---------|-------|
| Drain-Source Voltage  | V <sub>DS</sub>                   | -20     | V     |
| Gate-Source Voltage   | V <sub>GS</sub>                   | +8      | V     |
| Continuous Drain Current  | I <sub>D</sub>                    | -1.5    | A     |
| Pulsed Drain Current <sup>(Note 4)</sup>                        | I <sub>DM</sub>                   | -4      | A     |
| Power Dissipation   | T <sub>a</sub> =25°C              | 1.25    | W     |
|   | Derate above 25°C                 | 10      | mW/°C |
| Operating Junction and Storage Temperature Range                | T <sub>J</sub> , T <sub>STG</sub> | -55~150 | °C    |
| Thermal resistance<br>- Junction to Ambient <sup>(Note 3)</sup> | R <sub>θJA</sub>                  | 100     | °C/W  |



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## Electrical Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

| PARAMETER   | SYMBOL       | TEST CONDITION   | MIN. | TYP.      | MAX.     | UNITS     |
|---|--------------|--|------|-----------|----------|-----------|
| <b>Static</b>   |              |  |      |           |          |           |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$   | $V_{GS}=0V, I_D=-250\mu A$   | -20  | -         | -        | V         |
| Gate Threshold Voltage                                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250\mu A$   | -0.5 | -0.64     | -1.0     | V         |
| Drain-Source On-State Resistance                      | $R_{DS(on)}$ | $V_{GS}=-4.5V, I_D=-1.5A$  | -    | 240       | 325      | $m\Omega$ |
|   |              | $V_{GS}=-2.5V, I_D=-1.2A$  | -    | 295       | 420      |           |
|   |              | $V_{GS}=-1.8V, I_D=-0.5A$  | -    | 405       | 600      |           |
| Zero Gate Voltage Drain Current                       | $I_{DSS}$    | $V_{DS}=-20V, V_{GS}=0V$   | -    | -0.02     | -1       | $\mu A$   |
| Gate-Source Leakage Current                           | $I_{GSS}$    | $V_{GS}=\pm 8V, V_{DS}=0V$   | -    | $\pm 3.5$ | $\pm 10$ | $\mu A$   |
| <b>Dynamic</b>  |              |  |      |           |          |           |
| Total Gate Charge                                     | $Q_g$        | $V_{DS}=-10V, I_D=-1.5A,$<br>$V_{GS}=-4.5V$ (Note 1,2)                   | -    | 1.7       | -        | $nC$      |
| Gate-Source Charge                                    | $Q_{gs}$     |  | -    | 0.35      | -        |           |
| Gate-Drain Charge                                     | $Q_{gd}$     |  | -    | 0.43      | -        |           |
| Input Capacitance                                     | $C_{iss}$    | $V_{DS}=-10V, V_{GS}=0V,$<br>$f=1.0MHz$                                  | -    | 165       | -        | $pF$      |
| Output Capacitance                                    | $C_{oss}$    |  | -    | 25        | -        |           |
| Reverse Transfer Capacitance                          | $C_{rss}$    |  | -    | 14.7      | -        |           |
| <b>Switching</b>                                      |              |  |      |           |          |           |
| Turn-On Delay Time                                    | $t_{d(on)}$  | $V_{DD}=-10V, I_D=-1.5A,$<br>$V_{GS}=-4.5V,$<br>$R_G=6\Omega$ (Note 1,2) | -    | 11        | -        | $ns$      |
| Turn-On Rise Time                                     | $t_r$        |  | -    | 38        | -        |           |
| Turn-Off Delay Time                                   | $t_{d(off)}$ |  | -    | 130       | -        |           |
| Turn-Off Fall Time                                    | $t_f$        |  | -    | 75        | -        |           |
| <b>Drain-Source Diode</b>                             |              |  |      |           |          |           |
| Maximum Continuous Drain-Source Diode Forward Current | $I_S$        | ---  | -    | -         | -1.6     | A         |
| Diode Forward Voltage                                 | $V_{SD}$     | $I_S=-1.6A, V_{GS}=0V$   |      | -1.03     | -1.2     | V         |

### NOTES:

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.



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## TYPICAL CHARACTERISTIC CURVES

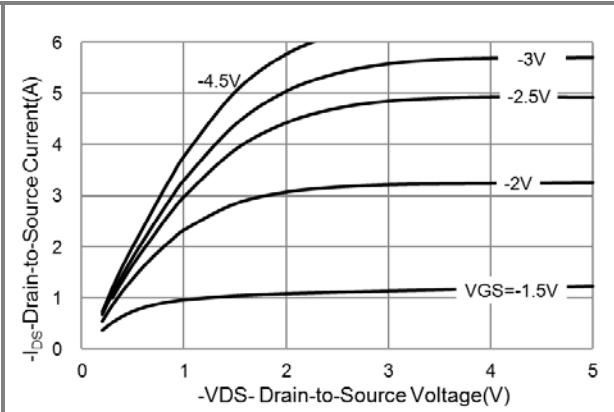


Fig.1 On-Region Characteristics

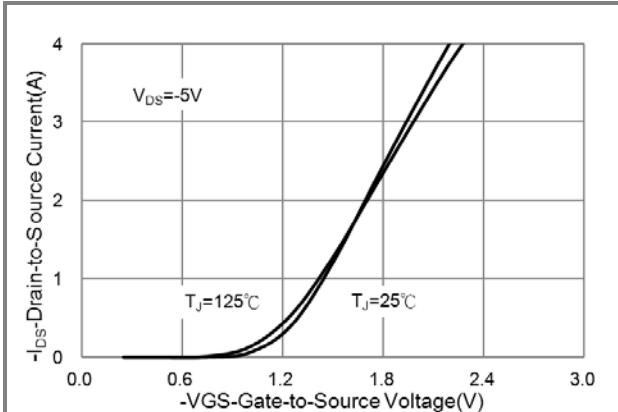


Fig.2 Transfer Characteristics

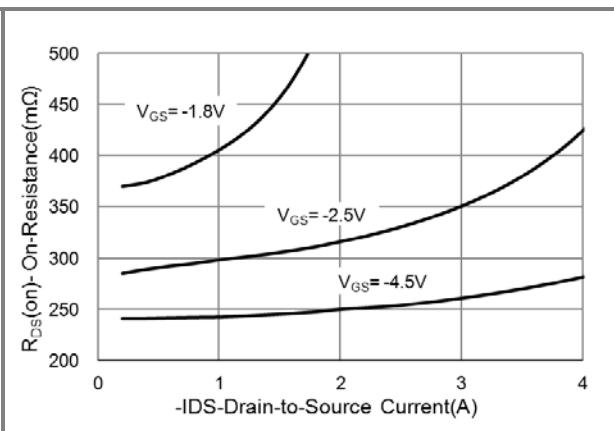


Fig.3 On-Resistance vs. Drain Current

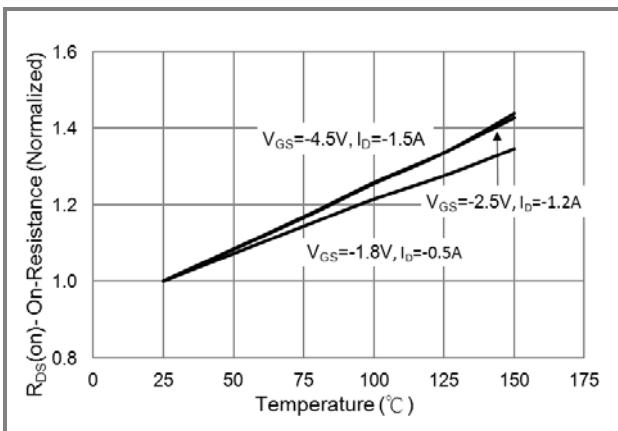


Fig.4 On-Resistance vs. Junction temperature

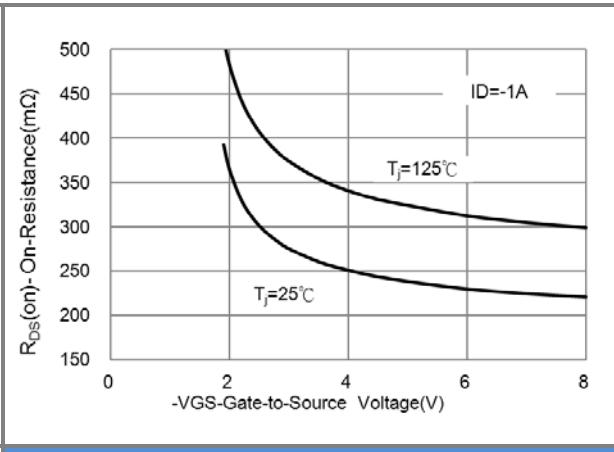


Fig.5 On-Resistance Variation with VGS.

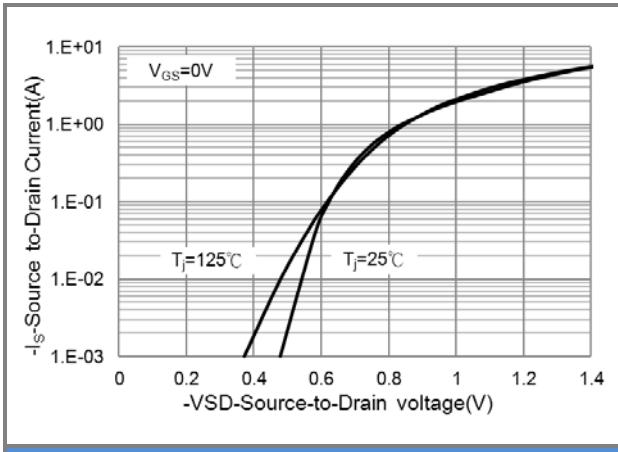


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

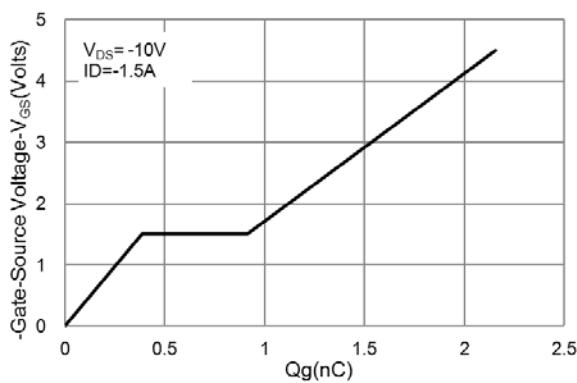


Fig.7 Gate-Charge Characteristics

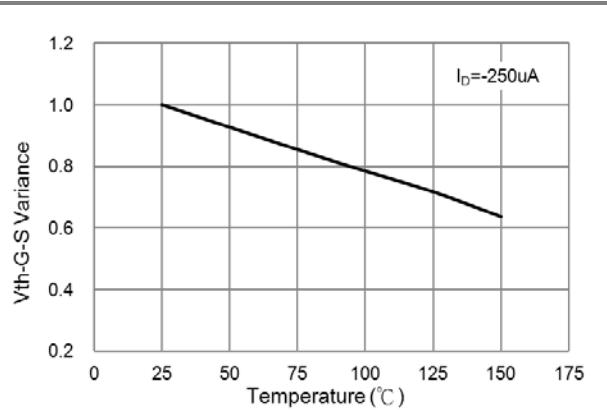


Fig.8 Threshold Voltage Variation with Temperature.

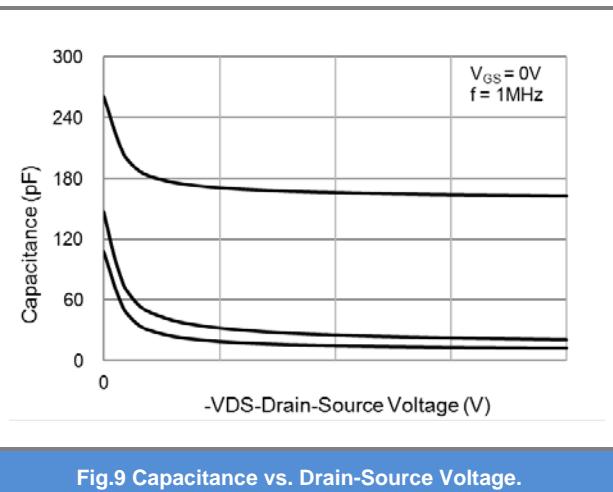


Fig.9 Capacitance vs. Drain-Source Voltage.

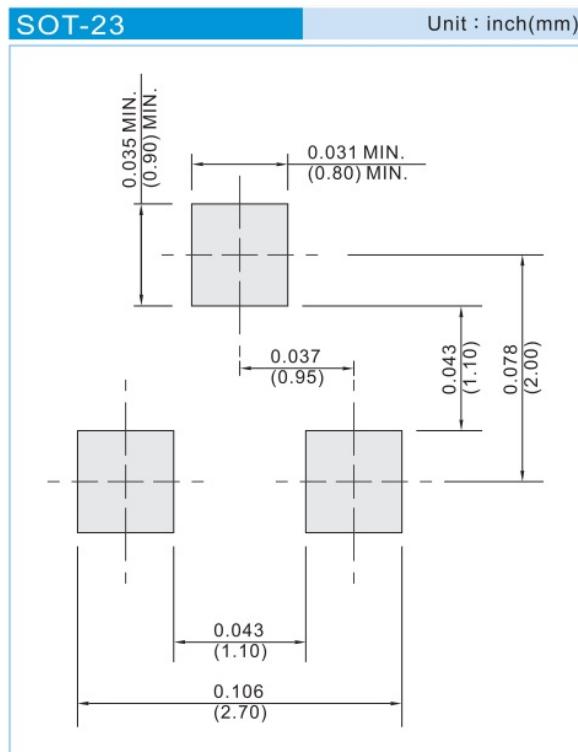


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## PART NO PACKING CODE VERSION

| PART NO PACKING<br>CODE VERSION | Package Type | Packing type       | Marking | Version      |
|---------------------------------|--------------|--------------------|---------|--------------|
| PJA3431_R1_00001                | SOT-23       | 3K pcs / 7" reel   | A31     | Halogen free |
| PJA3431_R2_00001                | SOT-23       | 12K pcs / 13" reel | A31     | Halogen free |

## MOUNTING PAD LAYOUT





## PJA3431

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